

^{127}Sn IT decay (4.52 μs) 2000Pi03,2004Ga24

Type	Author	History Citation	Literature Cutoff Date
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Parent: ^{127}Sn : E=1826.67 16; $J^\pi=(19/2^+)$; $T_{1/2}=4.52 \mu\text{s}$ 15; %IT decay=100.0

2004Ga24: $^{235}\text{U}(\text{n},\text{F})$ E=th, on-line mass separation; γ , β , $\gamma\gamma$ coin, $\beta\gamma$ coin.

2000Pi03: $^{233}\text{U}(\text{n},\text{F})$, $^{239}\text{Pu}(\text{n},\text{F})$, E=th, on-line mass separation; γ , ce, $\gamma\gamma$ coin, γ -ce coin, ce-ce coin.

An unknown excited state with half-life of 3.1 μs 9 has been proposed by 1980De35 from $\beta\gamma(t)$ results for 715 γ and 1094 γ , which have equal delayed intensities.

The decay scheme is proposed at first by 2000Pi03. The detail of decay scheme including the 16.52 keV isomeric transition and 5 other γ -rays is reported by 2004Ga24.

 ^{127}Sn Levels

E(level) [†]	J^π [‡]	$T_{1/2}$ [#]	Comments
0.0	11/2 ⁻		
646.34 4	(9/2) ⁻		
1094.60 15	(15/2) ⁻		
1242.79 13	(13/2) ⁻		
1625.32 19			
1810.12 15	(15/2 ⁺)		No β feeding to this level was assumed.
1826.64 16	(19/2 ⁺)	4.52 μs 15	$T_{1/2}$: weighted average of 4.4 μs 2 (2008Lo07), 4.8 μs 3 (2004Ga24) and 4.5 μs 3 (2000Pi03); other: 3.1 μs 9 (1980De35).

[†] From adopted level.

[‡] Spin and parity were estimated by analogy to ^{123}Sn isomer.

[#] $\gamma(t)$ from ^{127}Sn produced by $^9\text{Be}(^{238}\text{U},\text{F})$ and $^9\text{Be}(^{136}\text{Xe},\text{X})$ (2008Lo07); $\gamma(t)$ from ^{127}Sn produced by $^{233}\text{U}(\text{n},\text{F})$ and $^{239}\text{Pu}(\text{n},\text{F})$ (2000Pi03); from $\beta\gamma(t)$ delayed coincidence (2004Ga24): for the 4.52 μs isomer.

 $\gamma(^{127}\text{Sn})$

I_γ normalization: From $I(\gamma+\text{ce})(732.04\gamma+184.81\gamma+567.26\gamma+715.52\gamma) - I(\gamma+\text{ce})(236.0\gamma)=100$. The 236.0 γ is the transition to the 1810.13 state from the 2045.98 state in 1.04 s β decay. All I_γ from 2004Ga24 in 1.04 s β decay.

The cascade 184.8-979.1-646.34 γ 's were not reported by 2000Pi03.

E_γ ^{†@}	I_γ ^{‡&}	$E_i(\text{level})$	J_i^π	E_f	J_f^π	Mult.	α [#]	Comments
16.52 11	0.0245 16	1826.64	(19/2 ⁺)	1810.12	(15/2 ⁺)	E2	2.32×10^3 9	$\alpha(\text{L})=1.87 \times 10^3$ 7; $\alpha(\text{M})=384$ 15; $\alpha(\text{N}+\dots)=67.3$ 25 $\alpha(\text{N})=65.9$ 25; $\alpha(\text{O})=1.36$ 5 Mult.: From systematic of 19/2 ⁺ Sn isomers. In ^{129}Sn , the ratio of the K-x-ray intensity over L-electron intensity of isomeric transition is 0.7(2), compatible only with an E2 transition(2000Pi03). B(E2)=34 4 (2000Pi03).
184.81 13	1.62 19	1810.12	(15/2 ⁺)	1625.32		[M1]	0.1027	$\alpha(\text{K})=0.0889$ 13; $\alpha(\text{L})=0.01118$ 16; $\alpha(\text{M})=0.00219$ 3; $\alpha(\text{N}+\dots)=0.000448$ 7 $\alpha(\text{N})=0.000412$ 6; $\alpha(\text{O})=3.58 \times 10^{-5}$ 5 Mult.: M1 was assumed for transition intensity calculation, not used for J estimate.

Continued on next page (footnotes at end of table)

^{127}Sn IT decay (4.52 μs) 2000Pi03,2004Ga24 (continued) $\gamma(^{127}\text{Sn})$ (continued)

E_γ †@	I_γ ‡&	$E_i(\text{level})$	J_i^π	E_f	J_f^π	Mult.	Comments
567.26 15	10.2 10	1810.12	(15/2 ⁺)	1242.79	(13/2 ⁻)		
646.34 4	1.8 2	646.34	(9/2 ⁻)	0.0	11/2 ⁻	D,E2	I_γ : from the intensity balance of 184.8 γ and 979.1 γ (evaluator).
715.52 4	45 4	1810.12	(15/2 ⁺)	1094.60	(15/2 ⁻)		I_γ : From 1.04s ^{127}In decay (2000Pi03) for the 184.81, 567.26 and 715.52 γ .
732.04 11	9.4 7	1826.64	(19/2 ⁺)	1094.60	(15/2 ⁻)		
979.1 5	1.8 2	1625.32		646.34	(9/2 ⁻)		I_γ : from the intensity balance of 184.81 γ (evaluator).
1094.7 2	54 4	1094.60	(15/2 ⁻)	0.0	11/2 ⁻		I_γ : from the intensity balance of 715.52 γ and 732.04 γ (evaluator).
1242.71 15	10.2 10	1242.79	(13/2 ⁻)	0.0	11/2 ⁻		I_γ : from the intensity balance of 567.26 γ (evaluator).

† Proposed by (2004Ga24).

‡ From 1.04 s ^{127}In decay (2004Ga24), unless otherwise noted.

Theoretical conversion coefficients are calculated using BrIcc code for the multipolarity indicated.

@ Isomeric transition from the 1818(19/2⁺) level to the 1810(15/2⁺) level is not directly measured.

& For absolute intensity per 100 decays, multiply by 1.51 10.

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Decay Scheme

Intensities: $I_{(\gamma+ce)}$ per 100 parent decays
 %IT=100.0

Legend

- $I_{\gamma} < 2\% \times I_{\gamma}^{\text{max}}$
- $I_{\gamma} < 10\% \times I_{\gamma}^{\text{max}}$
- $I_{\gamma} > 10\% \times I_{\gamma}^{\text{max}}$
- Coincidence

